NSN 5961-00-226-8696

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-226-8696

Inclosure Material:

Metal

Overall Length:

Between 0.500 inches and 0.560 inches

Overall Diameter:

Between 1.240 inches and 1.280 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.312 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

150.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 25.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

7.50 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 1 threaded stud

Specification Data:

81349-mil-s-19500/102 government specification

Shelf Life:

N/a

Unit Of Measure:

NSN 5961-00-226-8696

Transistor - Page 2 of 2

Demilitarization:

No

Fiig:

A110a0

